



The PA-2 series of conductive cooled polygonal diode laser array is a high peak power product developed by RealLight for use at high temperatures of  $60^{\circ}$ C. The PA-2 series is composed of twelve hexagonally arranged stacks, with 1 ~ 4 bars in each stack, and each bar has a power of 100W/200W. Other wavelengths and packaging forms can be customized.

#### **Key Features**

- AuSn solder for packaging
- High temperature application
- High peak power
- High reliability

### **Applications**

Pumping source

Illumination

Laser processing

Scientific research

### **Technical Specifications**

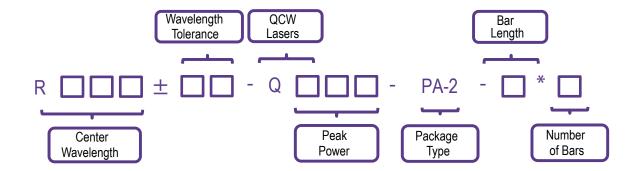
Optical Parameters			
Center Wavelength λ <sub>c</sub> (nm)	790-812		
Wavelength Tolerance δλ <sub>c</sub> (nm)	±3		
Output Power per Bar(W)	100	200	
Number of Horizontal Arrays	2		
Array-to-Array Pitch	3		
Number of Bars per Stack	1-4	1-3	
Bar-to-Bar Pitch(mm)	0.43	0.55	
Spectral Width(FWHM)(nm)	<6		
Fast Axis Divergence Angle(FWHM)(°)	≤40		
Slow Axis Divergence Angle (FWHM) (°)	≤10		
Wavelength Temperature Coefficient(nm/˚C)	~0.3		
Electrical Pa	rameters		
EO Conversion Efficiency (%)	≥50		
Threshold Current Ith (A)	≤20	≤30	
Operating Current I <sub>op</sub> (A)	100	220	
Operating Voltage V <sub>op</sub> of each Bar(V)	≤2	≤2.1	
Duty Cycle(%)	≤0.8%@4800W	≤0.6%@7200W	
Pulse Width(µs)	≤300		
Repetition Rate (Hz)	≤25	≤20	
Environment F	Parameters		
Operating Temperature(°C)	-40	-40~65	
Storage Temperature(°C)	-45	-45~85	

- 1. Wavelengths from 940nm to 960nm available upon request.
- 2. Custom number of bars, bar-to-bar pitch, and stack-to-stack pitch are available upon request.
- 3. The installation and wiring can be customized to meet the customer's requirements.
- 4. All the data in the above table are the typical values obtained from the tests at room temperature of 25 °C, and the final data is subject to the final test report.





# Part Numbering Schema



# Mechanical Drawings (in mm)

